

Technical Data Green Products

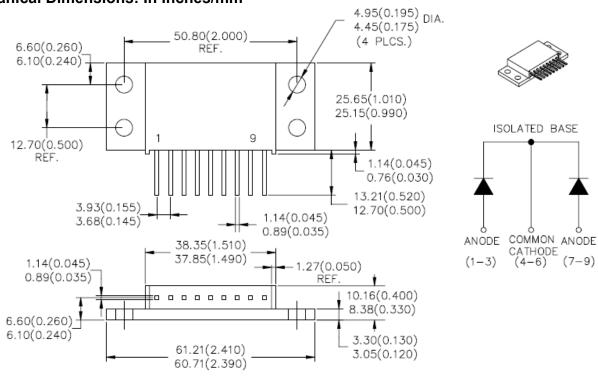
Data Sheet N1180, Rev. -

152CMQ030 SCHOTTKY RECTIFIER

Applications:

- Switching power supply Converters Free-Wheeling diodes Reverse battery protection Features:
 - 150 °C T_J operation
 - Isolated heatsink
 - . Multiple leads per terminal for high frequency, high current PC board mounting
 - · Low profile, high current package
 - Center tap module
 - Low forward voltage drop
 - High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 - High frequency operation
 - Guard ring for enhanced ruggedness and long term reliability
 - This is a Pb Free Device
 - All SMC parts are traceable to the wafer lot
 - Additional testing can be offered upon request

Mechanical Dimensions: In Inches/mm



TO-249(9 pin)

MARKING, MOLDING RESIN

Marking for 152CMQ030, 1st row SS YYWWL, 2nd row 152CMQ030, 3rd row 1 2 3 (Pin) Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL: 94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	VRWM	-	30	V
Max. Average Forward*	I _{F(AV)}	50% duty cycle @T _C = 85°C, rectangular wave form	150	А
Max. Peak One Cycle Non- Repetitive Surge Current (peg leg)	I _{FSM}	8.3 ms, half Sine pulse	1200	А
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =15A,L=0.6mH	68	mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max.V _A =1.5×V _R typical	15	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	 @ 75A, Pulse, T_J = 25 °C @ 150A, Pulse, T_J = 25 °C 	0.55 0.69	V
	V_{F2}	 @ 75A, Pulse, T_J = 75 °C @ 150A, Pulse, T_J = 75 °C 	0.47 0.66	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	5	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	280	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	3700	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	9.2	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	1.0	°C/W
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.5	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.10	°C/W
Mounting Torque	Тм	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	56	g
Case Style	TO-249(9 pin)			

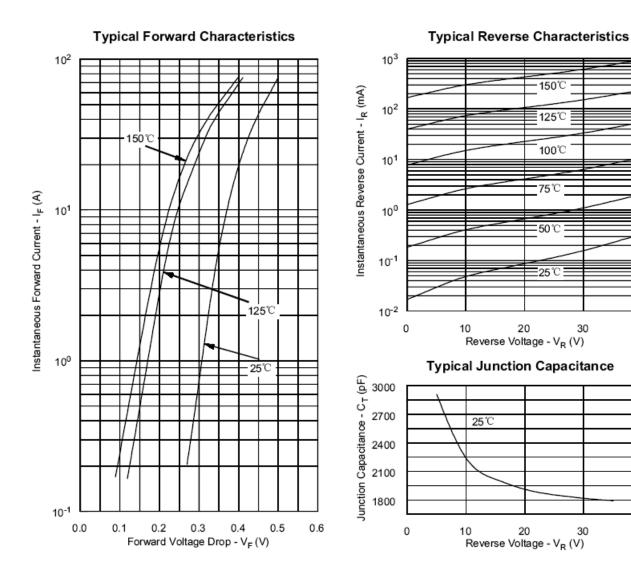
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